EXHIBIT G



(12) United States Patent

Banerjee et al.

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(54) HIGH PERFORMANCE SI-GE DEVICE MODULE WITH CMOS TECHNOLOGY

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(*) Notice: Subject to any disclaimer, the term of this

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(21) Appl. No.: 10/288,410

(22) Filed: Nov. 5, 2002

(51) Int. Cl.⁷ H01L 31/117

(52) **U.S. Cl.** **257/616**; 257/18; 257/19

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Primary Examiner—David Nelms Assistant Examiner—Tu-Tu Ho

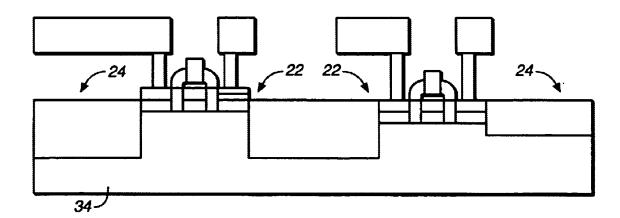
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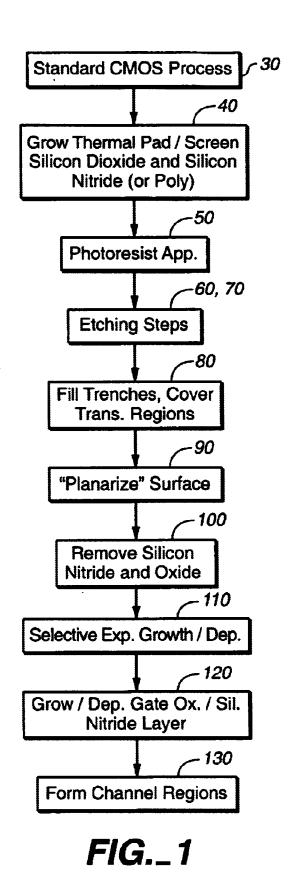
(57) ABSTRACT

A semiconductor device wherein some parts of a circuit are disposed on Si—Ge regions and others are implemented in Silicon substrate regions of the chip. The Si—Ge region provides that carrier flow is forced to the surface channel region which helps reduce short channel effects. A method of making such a semiconductor device is also provided and includes steps of forming a thermal oxide layer on a Silicon substrate, masking at least a portion of the thermal oxide layer, removing at least a portion of the thermal oxide layer in order to expose a portion of the Silicon substrate, epitaxially growing an Si—Ge layer on the exposed portion of the Silicon substrate, epitaxially growing a Silicon layer on the Si—Ge layer, and continuing manufacture of the device by forming a circuit on the Si—Ge regions and non-Si—Ge regions of the semiconductor device.

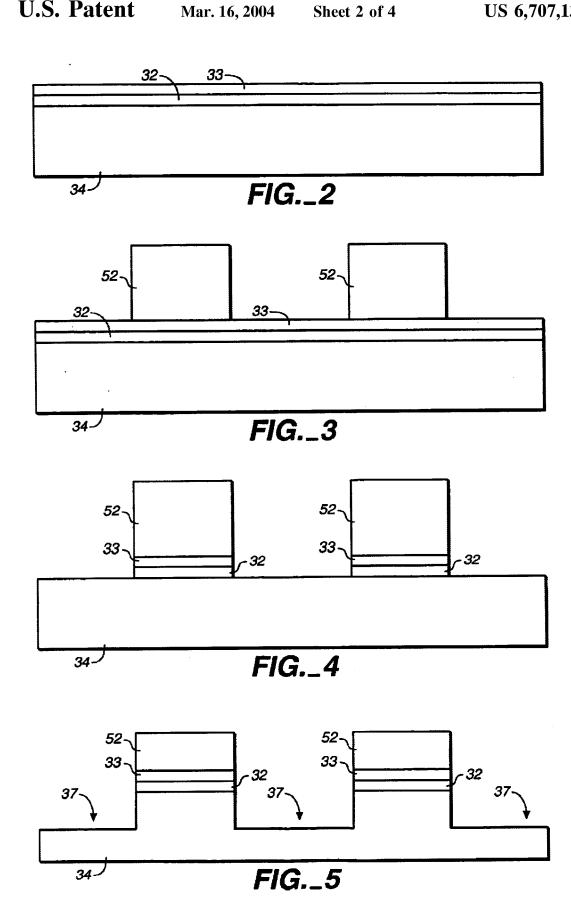
18 Claims, 4 Drawing Sheets



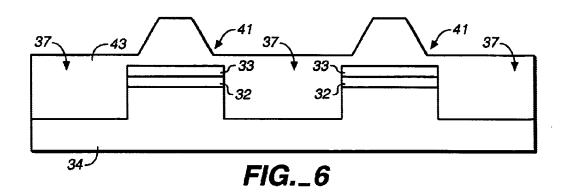




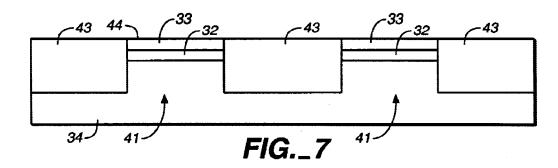
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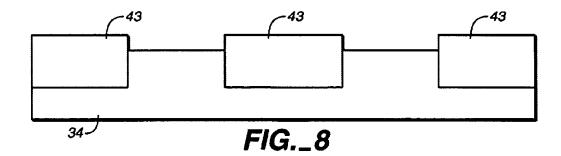


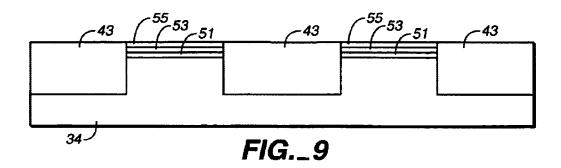




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